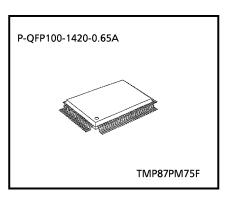
#### CMOS 8-Bit Microcontroller

### TMP87PM75F

The 87PM75 is a One-Time PROM microcontroller with low-power 256 K bits (32 Kbytes) electrically programmable read only memory for the 87CH75/CM75 system evaluation. The 87PM75 is pin compatible with the 87CH75/CM75. The operations possible with the 87CH75/CM75 can be performed by writing programs to PROM. The 87PM75 can write and verify in the same way as the TC57256AD using an adaptor socket BM11124 and an EPROM programmer.

| Part No.   | OTP          | RAM         | Package             | Adaptor Socket |
|------------|--------------|-------------|---------------------|----------------|
| TMP87PM75F | 32 K × 8-bit | 1 K × 8-bit | P-QFP100-1420-0.65A | BM11124        |



For a discussion of how the reliability of microcontrollers can be predicted, please refer to Section 1.3 of the chapter entitled Quality and Reliability Assurance / Handling Precautions.

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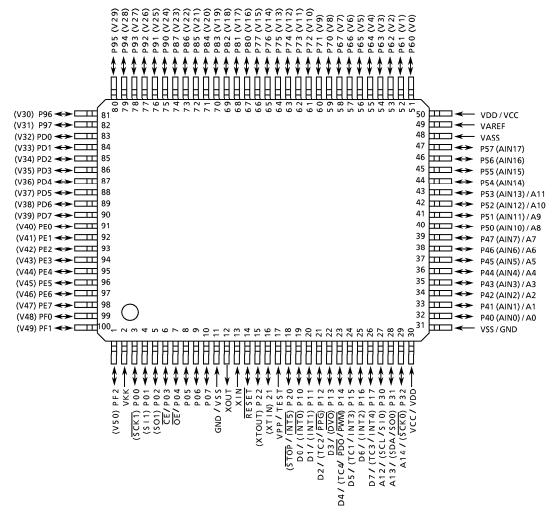
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3-75-133 2000-12-15

# Pin Assignments (Top View)

P-QFP100-1420-0.65A



Note: All VDDs should be connected externally for keeping the same voltage level.

### **Pin Function**

The 87PM75 has two modes: MCU and PROM.

(1) MCU mode

In this mode, the 87PM75 is pin compatible with the 87CH75/CM75 (fix the TEST pin at low level).

# (2) PROM mode

| Pin Name<br>(PROM mode)       | Input / Output | Functions   | Pin Name<br>(MCU mode)           |  |  |  |
|-------------------------------|----------------|---|----------------------------------|--|--|--|
| A14 to A12 A11 to A8 A7 to A0 | Input          | PROM address inputs                                     | P32 to P30 P53 to P50 P47 to P40 |  |  |  |
| D7 to D0                      | I/O            | PROM data input/outputs                                 | P17 to P10                       |  |  |  |
| CE                            | lanut          | Chip enable signal input (active low)                   | P03                              |  |  |  |
| ŌĒ                            | Input          | Output enable signal input (active low)                 | P04                              |  |  |  |
| VPP                           |                | + 12.5 V / 5 V (Program supply voltage)                 | TEST                             |  |  |  |
| vcc                           | Power supply   | +5V   | VDD                              |  |  |  |
| GND                           |                | 0 V   | VSS                              |  |  |  |
| P57 to P54                    |                | Pull-up with resistance for input processing            |                                  |  |  |  |
| P05, P02, P01                 |                | PROM mode setting pin. Be fixed at high level.          |                                  |  |  |  |
| P21                           | I/O            | Thorntone setting pin. Be fixed acting rever.           |                                  |  |  |  |
| P07, P06, P00                 | 1, 0           |   |                                  |  |  |  |
| P22, P20                      |                | PROM mode setting pin. Be fixed at low level.           |                                  |  |  |  |
| RESET                         |                |   |                                  |  |  |  |
| XIN                           | Input          | Connect an 8 MHz oscillator to stabilize the internal   | state                            |  |  |  |
| XOUT                          | Output         | Connect and own is oscillated to stabilize the internal | state.                           |  |  |  |
| PF2 to PF0                    |                |   |                                  |  |  |  |
| PE7 to PE0                    |                |   |                                  |  |  |  |
| PD7 to PD0                    |                |   |                                  |  |  |  |
| P97 to P90                    | I/O            | Open  |                                  |  |  |  |
| P87 to P80                    |                |   |                                  |  |  |  |
| P77 to P70                    |                |   |                                  |  |  |  |
| P67 to P60                    |                |   |                                  |  |  |  |
| VKK                           |                |   |                                  |  |  |  |
| VAREF                         | Power supply   | 0 V (GND)   |                                  |  |  |  |
| VASS                          |                |   |                                  |  |  |  |

#### **OPERATIONAL DESCRIPTION**

The following explains the 87PM75 hardware configuration and operation. The configuration and functions of the 87PM75 are the same as those of the 87CH75/M75, except in that a one-time PROM is used instead of an on-chip mask ROM.

The 87PM75 is placed in the *single-clock* mode during reset. To use the dual-clock mode, the low-frequency oscillator should be turned on by executing [SET (SYSCR2). XTEN] instruction at the beginning of the program.

#### 1. OPERATING MODE

The 87PM75 has two modes: MCU and PROM.

#### 1.1 MCU Mode

The MCU mode is activated by fixing the TEST / VPP pin at low level.

In the MCU mode, operation is the same as with the 87CH75/M75 (the TEST / VPP pin cannot be used open because it has no built-in pull-down resistance).

### 1.1.1 Program Memory

The 87PM75 has a  $32K \times 8$ -bit (addresses  $8000_H$ -FFFF<sub>H</sub> in the MCU mode, addresses  $0000_H$ -7FFF<sub>H</sub> in the PROM mode) of program memory (OTP).

The use the 87PM75 as the system evaluation for the 87CH75/CM75, the program should be writen to the program memory area as shown in Figure 1-1.

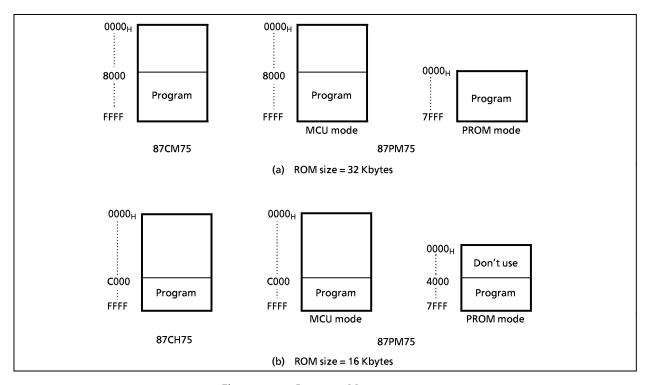


Figure 1-1. Program Memory Area

Note: Either write the data  $FF_H$  to the unused area or set the PROM programmer to access only the program storage area.

### 1.1.2 Data Memory

The 87PM75 has an on-chip  $1k \times 8$ -bit data memory (static RAM).

# 1.1.3 Input/Output Circuitry

### (1) Control pins

The control pins of the 87PM75 are the same as those of the 87CH75/CM75 except that the TEST pin has is no built-in pull-down resistance.

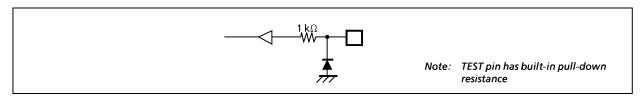


Figure 1-2. TEST Pin

## (2) I/O ports

The I/O circuitries of 87PM75 I/O ports are the same as the code A type I/O circuitries of the 87CH75/M75.

Whe using as an evaluator of other I/O code D, external pull-down resistors are required.

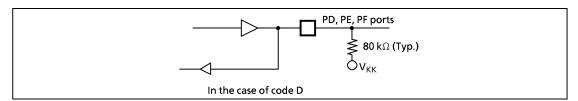


Figure 1-3. I/O Circuitry Code and External Circuitry

#### 1.2 PROM Mode

The PROM mode is activated by setting the pins TEST, RESET and the ports P07-P00, P22-P20 as shown in Figure 1-4. The PROM mode is used to write and verify programs with a general-purpose PROM programmer. The high-speed programming mode I and II can be used for program operation. The 87PM75 is not supported an electric signature mode, so the ROM type must be set to TC57256AD. Set the adaptor socket switch to "N".

Note: Please set the high-speed programming mode accoding to each manual of PROM programmer.

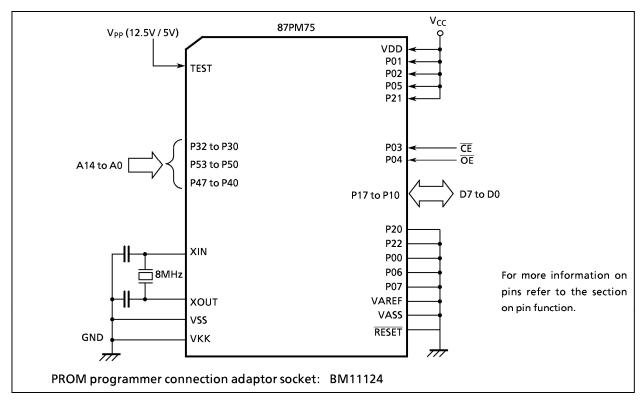


Figure 1-4. Setting for PROM Mode

# 1.2.1 Programming Flowchart (High-speed Programming Mode-I)

The high-speed programming mode is achieved by applying the program voltage (+ 12.5V) to the VPP pin when Vcc = 6V. After the address and input data are stable, the data is programmed by applying a single 1ms program pulse to the  $\overline{CE}$  input. The programmed data is verified. If incorrect, another 1ms program pulse is applied and then the programmed data is verified. This process should be repeated (up to 25 times) until the program operates correctly. Programming for one address is ended by applying additional program pulse with width 3 times that needed for initial programming (number of programmed times × 1ms). After that, change the address and input data, and program as before. When programming has been completed, the data in all addresses should be verified with Vcc = Vpp = 5V.

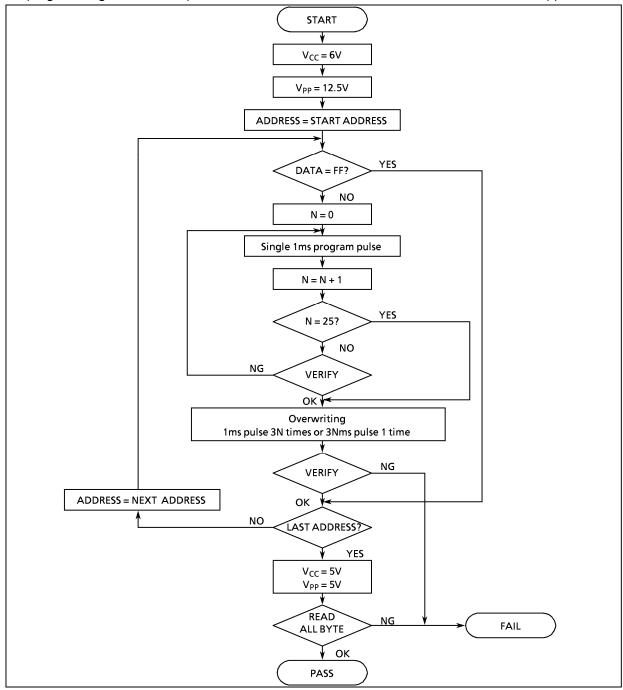


Figure 1-5. Flow Chart of High-speed Programming Mode - I

# 1.2.2 Programming Flowchart (High-speed Programming Mode-II)

The high-speed programming mode is achieved by applying the program voltage (  $\pm$  12.75 V) to the Vpp pin when Vcc = 6.25 V. After the address and input data are stable, the data is programmed by applying a single 0.1ms program pulse to the  $\overline{\text{CE}}$  input. The programmed data is verified. If incorrect, another 0.1ms program pulse is applied and then the programmed data is verified. This process should be repeated (up to 25 times) until the program operates correctly. After that, change the address and input data, and program as before. When programming has been completed, the data in all addresses should be verified with Vcc = Vpp = 5 V.

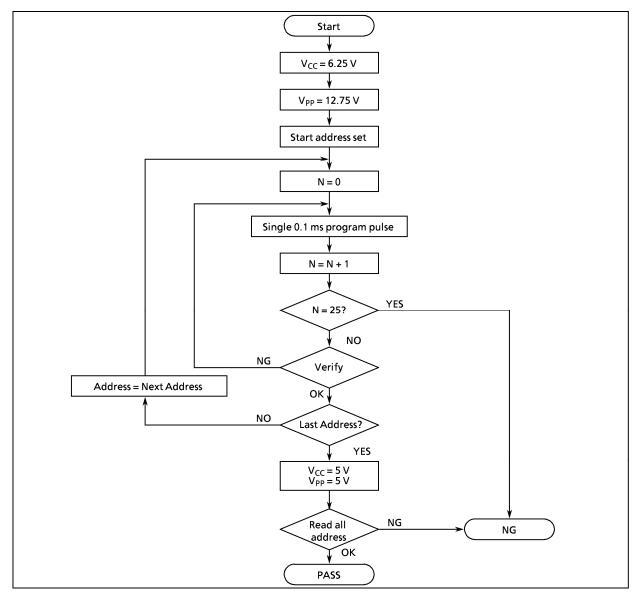


Figure 1-6. Flowchart of High-speed Programming Mode - II

## 1.2.3 Writing Method for General-purpose PROM Program

(1) Adapters

BM11124: TMP87PM75F

(2) Adapter setting Switch (SW1) is set to side N.

#### (3) PROM programmer specifying

i) PROM type is specified to TC57256AD.

Writing voltage: 12.5 V (high-speed program I mode) 12.75 V (high-speed program II mode)

ii) Data transfer (copy) (note 1)

In TMP87PM75, EPROM is within the addresses 0000<sub>H</sub> to 7FFF<sub>H</sub>. Data is required to be transferred (copied) to the addresses where it is possible to write. The program area in MCU mode and PROM mode is referred to "Program memory area" in Figure 1-1.

Ex. In the block transfer (copy) mode, executed as below.

ROM capacity of 32KB: transferred addresses  $8000_H$  to FFFF<sub>H</sub> to addresses  $0000_H$  to 7FFF<sub>H</sub> ROM capacity of 16KB: transferred addresses  $C000_H$  to FFFF<sub>H</sub> to addresses  $4000_H$  to 7FFF<sub>H</sub>

iii) Writing address is specified. (note 1)

Start address:  $0000_H$  (When ROM capacity of 16KB, start address is  $4000_H$ ) End address:  $7FFF_H$ 

(4) Writing

Writing/Verifying is required to be executed in accordance with PROM programmer operating procedure.

- Note 1: The specifying method is referred to the PROM programmer description. Either write the data  $FF_H$  to addresses  $0000_H$  to  $3FFF_H$  when ROM capacity of 16KB.
- Note 2: When MCU is set to an adapter or the adapter is set to PROM programmer, a position of pin 1 must be adjusted. If the setting is reserved, MCU, the adapter and PROM program is damaged.
- Note 3: The TMP87PM75 does not support the electric signature mode (hereinafter referred to as "signature"). If the signature is used in PROM program, a device is damaged due to applying  $12V \pm 0.5V$  to the address pin 9 (A9). The signature must not be used.

#### **Electrical Characteristics**

**Absolute Maximum Ratings** 

 $(V_{SS} = 0 V)$ 

| Parameter                       | Symbol              | Pins                            | Ratings                                | Unit  |
|---------------------------------|---------------------|---------------------------------|--|-------|
| Supply Voltage                  | $V_{DD}$            |                                 | - 0.3 to 6.5                           | V     |
| Program Voltage                 | $V_{PP}$            | TEST / VPP                      | - 0.3 to 13.0                          | ٧     |
| Input Voltage                   | $V_{IN}$            |                                 | - 0.3 to V <sub>DD</sub> + 0.3         | <     |
| Output Voltage                  | V <sub>OUT1</sub>   | P2, P3, P4, P5, P6, XOUT, RESET | - 0.3 to V <sub>DD</sub> + 0.3         |       |
|                                 | V <sub>OUT3</sub>   | Source open drain ports         | $V_{DD} - 40 \text{ to } V_{DD} + 0.3$ | \ \ \ |
| 0 (0 )                          | I <sub>OUT1</sub>   | P15 to P17, P3, P4, P5          | 3.2                                    |       |
|                                 | I <sub>OUT2</sub>   | P0, P10 to P14, P2              | 30                                     | ا ا   |
| Output Current (Per 1 pin)      | I <sub>OUT3</sub>   | P8, P9, PD, PE, PF              | - 12                                   | mA    |
|                                 | I <sub>OUT4</sub>   | P6, P7                          | - 25                                   |       |
|                                 | $\Sigma I_{OUT1}$   | P15 to P17, P3, P4, P5          | 60                                     |       |
| Output Current (Total)          | Σ I <sub>OUT2</sub> | P0, P10 to P14, P2              | 160                                    | mA    |
|                                 | Σ I <sub>OUT3</sub> | P6, P7, P8, P9, PD, PE, PF      | - 200                                  |       |
| Power Dissipation [Topr = 25°C] | PD                  | Note 2                          | 1200                                   | mW    |
| Soldering Temperature (time)    | Tsld                |                                 | 260 (10 s)                             | °C    |
| Storage Temperature             | Tstg                |                                 | – 55 to 125                            | °C    |
| Operating Temperature           | Topr                |                                 | – 30 to 70                             | °C    |

Note 1: The absolute maximum ratings are rated values which must not be exceeded during operation, even for an instant. Any one of the ratings must not be exceeded. If any absolute maximum rating is exceeded, a device may break down or its performance may be degraded, causing it to catch fire or explode resulting in injury to the user. Thus, when designing products which include this device, ensure that no absolute maximum rating value will ever be exceeded.

Note 2: Power Dissipation (PD); For PD, it is necessary to decrease 14.3 mW/°C.

Note 3: All VDDs should be connected externally for keeping the same voltage level.

**Recommended Operating Conditions** 

 $(V_{SS} = 0 \text{ V}, \text{ Topr} = -30 \text{ to } 70^{\circ}\text{C})$ 

| Parameter          | Symbol            | Pins                    | (  | Conditions                       |                      | Max                  | Unit |
|--------------------|-------------------|-------------------------|--|----------------------------------|----------------------|----------------------|------|
|                    |                   |                         | 6 0.001  | NORMAL 1, 2 modes                | 4.5                  |                      |      |
|                    |                   |                         | fc = 8 MHz   | IDLE1, 2 modes                   | 4.5                  |                      |      |
| Supply Voltage     | $V_{DD}$          |                         | fs =   | SLOW mode                        | 2.7                  | 5.5                  | V    |
|                    |                   |                         | 32.768 kHz   | SLEEP mode                       | 2.7                  |                      |      |
|                    |                   |                         |  | STOP mode                        | 2.0                  |                      |      |
| Output Voltage     | V <sub>OUT3</sub> | Source open drain ports |  |                                  | V <sub>DD</sub> – 38 | $V_{DD}$             | ٧    |
|                    | V <sub>IH1</sub>  | Except hysteresis input | V <sub>DD</sub> ≥ 4.5 V<br>V <sub>DD</sub> < 4.5 V |                                  | $V_{DD} \times 0.70$ |                      |      |
| Input High Voltage | V <sub>IH2</sub>  | Hysteresis input        |  |                                  | $V_{DD} \times 0.75$ | V <sub>DD</sub>      | V    |
|                    | V <sub>IH3</sub>  |                         |  |                                  | $V_{DD} \times 0.90$ |                      |      |
|                    | $V_{IL1}$         | Except hysteresis input |  | / > / E \/                       |                      | $V_{DD} \times 0.30$ |      |
| Input Low Voltage  | $V_{IL2}$         | Hysteresis input        | \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \              | / <sub>DD</sub> ≥ 4.5 V          | 0                    | $V_{DD} \times 0.25$ | V    |
|                    | V <sub>IL3</sub>  |                         | \  | V <sub>DD</sub> <4.5 V           |                      | $V_{DD} \times 0.10$ |      |
|                    |                   | VIN VOLIT               | V <sub>DD</sub> :                                  | V <sub>DD</sub> = 4.5 V to 5.5 V |                      | 8.0                  | MHz  |
| Clock Frequency    | fc                | XIN, XOUT               | V <sub>DD</sub> = 2.7 V to 5.5 V                   |                                  | 0.4                  | 4.2                  |      |
|                    | fs                | XTIN, XTOUT             |  |                                  | 30.0                 | 34.0                 | kHz  |

Note 1: The recommended operating conditions for a device are operating conditions under which it can be guaranteed that the device will operate as specified. If the device is used under operating conditions other than the recommended operating conditions (supply voltage, operating temperature range, specified AC/DC values etc.), malfunction may occur. Thus, when designing products which include this device, ensure that the recommended operating conditions for the device are always adhered to.

Note 2: Clock frequency fc: Supply voltage range is specified in NORMAL 1/2 mode and IDLE 1/2 mode.

D.C. Characteristics

 $(V_{SS} = 0 \text{ V}, \text{ Topr} = -30 \text{ to } 70^{\circ}\text{C})$ 

| Parameter            | Symbol           | Pins                              | Conditions  | Min | Тур. | Max | Unit         |
|----------------------|------------------|-----------------------------------|---|-----|------|-----|--------------|
| Hysteresis Voltage   | V <sub>HS</sub>  | Hysteresis input                  |   | -   | 0.9  | -   | V            |
|                      | I <sub>IN1</sub> | TEST                              | V <sub>DD</sub> = 5.5 V   |     |      |     |              |
| Input Current        | I <sub>IN2</sub> | Open drain ports, Tri-state ports |   | -   | _    | ± 2 |              |
| input current        | I <sub>IN3</sub> | RESET, STOP                       | V <sub>IN</sub> = 5.5 V / 0 V                                   |     |      |     | μA           |
|                      | I <sub>IN4</sub> | PD, PE, PF ports (Note3)          |   | -   | -    | 80  |              |
| Input Resistance     | R <sub>IN2</sub> | RESET                             |   | 100 | 220  | 450 | kΩ           |
| Pull-down Resistance | $R_{K}$          | Source open drain ports           | $V_{DD} = 5.5 \text{ V}, V_{KK} = -30 \text{ V}$                | 50  | 80   | 110 | K77          |
| Output Leakage       | I <sub>LO1</sub> | Sink open drain ports             | $V_{DD} = 5.5 V, V_{OUT} = 5.5 V$                               | _   | _    | 2   |              |
| Current              | I <sub>LO2</sub> | Source open drain ports           | $V_{DD} = 5.5 \text{ V}, \ V_{OUT} = -32 \text{ V}$             | -   | -    | - 2 | μA           |
| Current              | I <sub>LO3</sub> | Tri-state ports                   | $V_{DD} = 5.5 \text{ V}, V_{OUT} = 5.5 \text{ V} / 0 \text{ V}$ | -   | -    | ± 2 |              |
| Output High Voltage  | V <sub>OH2</sub> | Tri-state ports                   | $V_{DD} = 4.5 \text{ V}, I_{OH} = -0.7 \text{ mA}$              | 4.1 | _    | _   | <sub>V</sub> |
| Output High Voltage  | V <sub>OH3</sub> | P8, P9, PD, PE, PF                | $V_{DD} = 4.5 \text{ V}, I_{OH} = -8 \text{ mA}$                |     | -    | _   | V            |
| Output Low Voltage   | V <sub>OL</sub>  | Except XOUT, P0, P10 to P14, P2   | $V_{DD} = 4.5 \text{ V}, I_{OL} = 1.6 \text{ mA}$               | -   | -    | 0.4 | V            |
| Output Low current   | I <sub>OL3</sub> | P0, P10 to P14, P2                | $V_{DD} = 4.5 \text{ V}, V_{OL} = 1.0 \text{ V}$                | -   | 20   | -   | mA           |
| Output High current  | I <sub>OH</sub>  | P6, P7                            | $V_{DD} = 4.5 \text{ V}, V_{OH} = 2.4 \text{ V}$                | -   | - 20 | _   | mA           |
| Supply Current in    |                  |                                   | V <sub>DD</sub> = 5.5 V   |     |      |     |              |
| NORMAL 1, 2 modes    |                  |                                   | fc = 8 MHz  | -   | 12   | 18  |              |
| Supply Current in    |                  |                                   | fs = 32.768 kHz   |     |      |     | mA           |
| IDLE 1, 2 modes      |                  |                                   | V <sub>IN</sub> = 5.3 V / 0.2 V                                 | -   | 6    | 9   |              |
| Supply Current in    | 1.               |                                   | $V_{DD} = 3.0 \text{ V}$  |     |      |     |              |
| SLOW mode            | I <sub>DD</sub>  |                                   |   | _   | 30   | 60  |              |
| Supply Current in    |                  |                                   | fs = 32.768 kHz   |     |      |     | $\mu$ A      |
| SLEEP mode           |                  |                                   | $V_{IN} = 2.8 \text{ V} / 0.2 \text{ V}$                        | _   | 15   | 30  |              |
| Supply Current in    |                  |                                   | V <sub>DD</sub> = 5.5 V   |     |      |     |              |
| STOP mode            |                  |                                   | V <sub>IN</sub> = 5.3 V / 0.2 V                                 | -   | 0.5  | 10  | μA           |

Note 1: Typical values show those at Topr =  $25^{\circ}$ C ,  $V_{DD}$  = 5 V.

Note 2: Input Current  $I_{IN1,l_{IN3}}$ ; The current through resistor is not included, when the input resistor (pull-up/pull-down) is contained.

A/D Conversion Characteristics

 $(V_{SS} = 0 \text{ V}, V_{DD} = 4.5 \text{ to } 6.0 \text{ V}, \text{ Topr} = -30 \text{ to } 70^{\circ}\text{C})$ 

| Parameter                | Symbol            | Conditions  | Min                   | Тур.            | Max  | Unit |
|--------------------------|-------------------|---|-----------------------|-----------------|--|------|
|                          | V <sub>AREF</sub> | V >25V  | V <sub>DD</sub> – 1.5 | _               | V <sub>DD</sub>  |      |
| Analog Reference Voltage | V <sub>ASS</sub>  | $V_{AREF} - V_{ASS} \ge 2.5 V$                            |                       | V <sub>SS</sub> | - V <sub>DD</sub> V <sub>SS</sub> - V <sub>AREF</sub> 0.5 1.0 - ±1 - ±1 - ±1 | ]    |
| Analog Input Voltage     | V <sub>AIN</sub>  |   | V <sub>ASS</sub>      | _               | V <sub>AREF</sub>  | ٧    |
| Analog Supply Current    | I <sub>REF</sub>  | V <sub>AREF</sub> = 5.5 V, V <sub>ASS</sub> = 0.0 V       | _                     | 0.5             | 1.0  | mA   |
| Nonlinearity Error       |                   |   | _                     | -               | ± 1  |      |
| Zero Point Error         |                   | $V_{DD} = 5.0 \text{ V}, V_{SS} = 0.0 \text{ V}$          | _                     | -               | ± 1  | ]    |
| Full Scale Error         |                   | V <sub>AREF</sub> = 5.000 V<br>V <sub>ASS</sub> = 0.000 V | _                     | _               | ± 1  | LSB  |
| Total Error              |                   |   | _                     | _               | ± 2  |      |

Note: Quantizing error is not contained in those errors.

### A.C. Characteristics

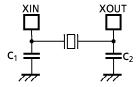
 $(V_{SS} = 0 \text{ V}, V_{DD} = 4.5 \text{ to } 5.5 \text{ V}, Topr = -30 \text{ to } 70^{\circ}\text{C})$ 

| Parameter                    | Symbol           | Conditions                    | Min   | Тур. | Max   | Unit    |
|------------------------------|------------------|-------------------------------|-------|------|-------|---------|
| Machine Cycle Time           |                  | In NORMAL1, 2 modes           | ٥٠    |      | 4.0   |         |
|                              |                  | In IDLE1, 2 modes             | 0.5   | _    | 10    |         |
|                              | t <sub>cy</sub>  | In SLOW mode                  | 117.6 |      | 122.2 | $\mu$ S |
|                              |                  | In SLEEP mode                 | 117.6 | _    | 133.3 |         |
| High Level Clock Pulse Width | t <sub>WCH</sub> | For external clock operation  |       |      |       |         |
| Low Level Clock Pulse Width  | t <sub>WCL</sub> | (XIN input), fc = 8 MHz       | 50    | _    | _     | ns      |
| High Level Clock Pulse Width | t <sub>WSH</sub> | For external clock operation  | 14.7  |      |       |         |
| Low Level Clock Pulse Width  | t <sub>WSL</sub> | (XTIN input), fs = 32.768 kHz | 14.7  | _    | ı     | μS      |

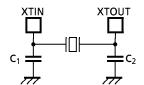
# Recommended Oscillating Conditions

 $(V_{SS} = 0 \text{ V}, V_{DD} = 4.5 \text{ to } 5.5 \text{ V}, Topr = -30 \text{ to } 70^{\circ}\text{C})$ 

|                              |   | Oscillation | Oscillation    |                | Recommended Constant |      |  |
|------------------------------|---|-------------|----------------|----------------|----------------------|------|--|
| Parameter                    | Oscillator Recommended Oscillator Frequency |             | C <sub>1</sub> | C <sub>2</sub> |                      |      |  |
| Co<br>High-frequency         |   | 8 MHz       | KYOCERA        | KBR8.0M        |                      |      |  |
|                              | Ceramic Resonator                           |             | KYOCERA        | KBR4.0MS       | 30pF                 | 30pF |  |
|                              |   | 4 MHz       | MURATA         | CSA4.00MG      |                      |      |  |
| Oscillation                  |   | 8 MHz       | тоуосом        | 210B 8.0000    |                      |      |  |
|                              | Crystal Oscillator                          | 4 MHz       | тоуосом        | 204B 4.0000    | 20pF                 | 20pF |  |
| Low-frequency<br>Oscillation | Crystal Oscillator                          | 32.768 kHz  | NDK            | MX-38T         | 15pF                 | 15pF |  |



(1) High-frequency Oscillation



(2) Low-frequency Oscillation

Note: An electrical shield by metal shied plate on the IC package should be recommend able in order to prevent the device from the high electric fieldstress applied for continuous reliable operation.

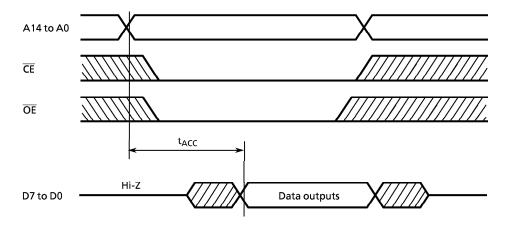
# D.C./A.C. Characteristics (PROM mode)

 $(V_{SS} = 0 V)$ 

# (1) Read Operation (Topr = -30 to $70^{\circ}$ C)

| Parameter                    | Symbol           | Conditions                    | Min                     | Тур.            | Max                    | Unit  |
|------------------------------|------------------|-------------------------------|-------------------------|-----------------|------------------------|-------|
| Input High Voltage           | V <sub>IH4</sub> |                               | V <sub>CC</sub> × 0.7   | _               | V <sub>CC</sub>        | ٧     |
| Input Low Voltage            | V <sub>IL4</sub> |                               | 0                       | -               | V <sub>CC</sub> × 0.12 | V     |
| Power Supply Voltage         | V <sub>CC</sub>  |                               | 4.75                    | 5.00            | 5.25                   | v     |
| Program Power Supply Voltage | V <sub>PP</sub>  |                               | V <sub>CC</sub> – 0.6 V | V <sub>CC</sub> | V <sub>CC</sub> +6.0   | \ \ \ |
| Address Access Time          | t <sub>ACC</sub> | V <sub>CC</sub> = 5.0 ± 0.5 V | -                       | 1.5 tcyc + 300  | _                      | ns    |

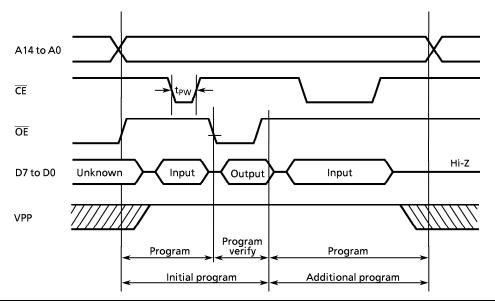
Note: tcyc = 500 ns at 8 MHz



**Timing Waveforms of Read Operation** 

### (2) High-Speed Programming Operation (Topr = $25 \pm 5^{\circ}$ C)

| Parameter                    | Symbol           | Conditions  | Min                   | Тур. | Max                    | Unit |
|------------------------------|------------------|---|-----------------------|------|------------------------|------|
| Input High Voltage           | V <sub>IH4</sub> |   | V <sub>CC</sub> × 0.7 | -    | V <sub>CC</sub>        | ٧    |
| Input Low Voltage            | V <sub>IL4</sub> |   | 0                     | _    | V <sub>CC</sub> × 0.12 | ٧    |
| Power Supply Voltage         | V <sub>CC</sub>  |   | 5.75                  | 6.0  | 6.25                   | ٧    |
| Program Power Supply Voltage | V <sub>PP</sub>  |   | 12.0                  | 12.5 | 13.0                   | ٧    |
| Initial Program Pulse Width  | t <sub>PW</sub>  | $V_{CC} = 6.0 \text{ V} \pm 0.25 \text{ V}$<br>$V_{PP} = 12.5 \pm 0.25 \text{ V}$ | 0.95                  | 1.0  | 1.05                   | ms   |



Note1: When  $V_{cc}$  power supply is turned on or after,  $V_{pp}$  must be increased. When  $V_{cc}$  power supply is turned off or before,  $V_{pp}$  must be decreased.

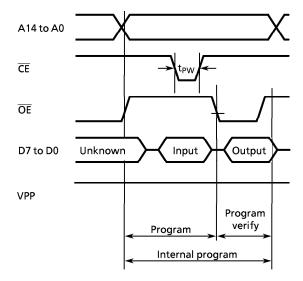
Note2: The device must not be set to the EPROM programmer or picked up from it under applying the program voltage (12.75 V  $\pm$  0.5 V) to the  $V_{pp}$  pin as the device is damaged.

Note3: Be sure to execute the recommended programing mode with the recommended programing adaptor. If a mode or an adaptor except the above, the misoperation sometimes occurs.

**Timing Waveforms of Programming Operation** 

### Program Operation (High speed write mode -II) (Topr = $25 \pm 5^{\circ}$ C)

| Parameter                   | Symbol           | Conditions  | Min                   | Тур.  | Max                    | Unit     |
|-----------------------------|------------------|---|-----------------------|-------|------------------------|----------|
| Input High Voltage          | V <sub>IH4</sub> |   | V <sub>CC</sub> × 0.7 | -     | V <sub>CC</sub>        | ٧        |
| Input Low Voltage           | V <sub>IL4</sub> |   | 0                     | _     | V <sub>CC</sub> × 0.12 | >        |
| Supply Voltage              | V <sub>CC</sub>  |   | 6.00                  | 6.25  | 6.50                   | >        |
| Program Supply Voltage      | V <sub>PP</sub>  |   | 12.50                 | 12.75 | 13.0                   | <b>V</b> |
| Initial Program Pulse Width | t <sub>PW</sub>  | $V_{CC} = 6.0 \text{ V} \pm 0.25 \text{ V}$<br>$V_{PP} = 12.5 \pm 0.25 \text{ V}$ | 0.095                 | 0.1   | 0.105                  | ms       |



When  $V_{cc}$  power supply is turned on or after,  $V_{pp}$  must be increased. When  $V_{cc}$  power supply is turned off or before,  $V_{pp}$  must be decreased. Note1:

Note2: The device must not be set to the EPROM programmer or picked up from it under applying

the program voltage (12.75 V  $\pm$  0.25 V) to the  $V_{pp}$  pin as the device is damaged.